

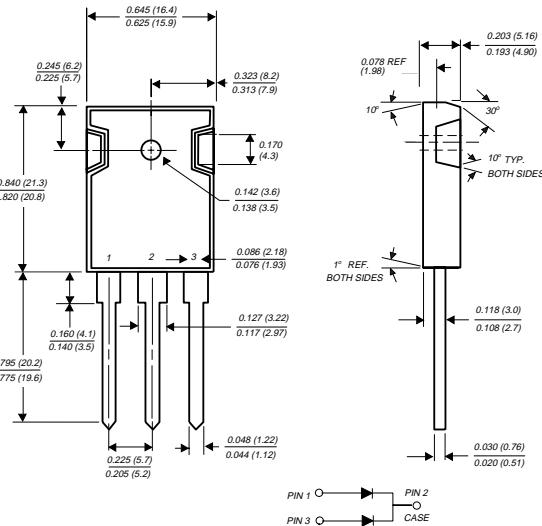
MBR3035PT THRU MBR3060PT

SCHOTTKY RECTIFIER

Reverse Voltage - 35 to 60 Volts

Forward Current - 30.0 Amperes

TO-247AD



FEATURES

- ♦ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ♦ Dual rectifier construction, positive center-tap
- ♦ Metal silicon junction, majority carrier conduction
- ♦ Low power loss, high efficiency
- ♦ High current capability, low forward voltage drop
- ♦ High surge capability
- ♦ For use in low voltage, high frequency inverters, free-wheeling, and polarity protection applications
- ♦ Guardring for overvoltage protection
- ♦ High temperature soldering guaranteed: 250°C/10 seconds, 0.17" (4.3mm) from case



MECHANICAL DATA

Case: JEDEC TO-247AD molded plastic body

Terminals: Lead solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Mounting Torque: 10 in.- lbs. max.

Weight: 0.2 ounce, 5.6 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	MBR3035PT	MBR3045PT	MBR3050PT	MBR3060PT	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	Volts
Maximum working peak reverse voltage	V _{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage	V _{DC}	35	45	50	60	Volts
Maximum average forward rectified current (SEE FIG. 1)	I _(AV)			30.0		Amps
Peak repetitive forward current per leg at T _c =105°C (rated V _R , square wave, 20 KHz)	I _{FRM}			30.0		Amps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}			200.0		Amps
Peak repetitive reverse surge current (NOTE 2)	I _{RRM}		2.0		1.0	Amps
Maximum instantaneous forward voltage per leg at: (NOTE 1) I _F =20A, T _c =25°C I _F =20A, T _c =125°C I _F =30A, T _c =25°C I _F =30A, T _c =125°C	V _F		—	0.75 0.65		Volts
0.60 0.76 0.72			— — —			
Maximum instantaneous reverse current at rated DC blocking voltage T _c =25°C per leg (NOTE 2)	I _R	1.0 60.0		5.0 100.0		mA
Maximum thermal resistance (NOTE 3)	R _{θJC}		1.4			°C/W
Voltage rate of change at (rated V _R)	dV/dt		10,000			V/μs
Operating junction temperature range	T _J		-65 to +150			°C
Storage temperature range	T _{STG}		-65 to +175			°C

NOTES:

(1) 2.0μs pulse width, f=1.0 KHz

(2) Pulse test: 300μs pulse width, 1% duty cycle

(3) Thermal resistance from junction to case per leg

RATINGS AND CHARACTERISTIC CURVES MBR3035PT THRU MBR3060PT

